TOSHIBA TFR7H

### TOSHIBA FAST RECOVERY DIODE SILICON DIFFUSED TYPE

# TFR7H

STROBO FLASHER APPLICATIONS (FAST RECOVERY)

Average Forward Current :  $I_{F(AV)} = 0.2A$ 

Reverse Voltage (DC)  $: V_{RM} = 500V$ 

Repetitive Peak Reverse Surge Voltage :  $V_{RRSM} = 1500V$ 

Reverse Recovery Time :  $t_{rr} = 10 \mu s$ 

#### **MAXIMUM RATINGS**

CHARACTERISTIC	SYMBOL	RATING	UNIT
Reverse Voltage (DC)	$v_{RM}$	500	V
Repetitive Peak Reverse Surge Voltage	V <sub>RRSM</sub>	1500	V
Average Forward Current	I <sub>F (AV)</sub>	0.2	A
Peak One Cycle Surge Forward Current (Non Repetitive)	I <sub>FSM</sub>	10	A
Junction Temperature	$T_{j}$	-40~125	$^{\circ}\mathrm{C}$
Storage Temperature Range	$\mathrm{T}_{\mathrm{stg}}$	-40~125	°C

1. ANODE 2. CATHODE **JEDEC EIAJ** TOSHIBA 3-3F2A

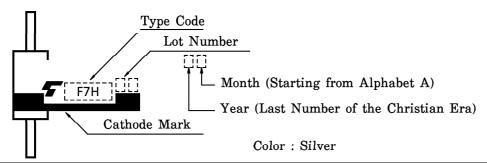
Unit in mm

Weight: 0.137g

# ELECTRICAL CHARACTERISTICS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Peak Forward Voltage	$ m V_{FM}$	$I_{\text{FM}} = 0.3 A$	_	_	1.50	V
Reverse Current	${ m I}_{ m RM}$	$V_{ m RM}$ = 500V	_	_	10	$\mu$ A
Repetitive Peak Reverse Surge Current	$I_{RRSM}$	$V_{ m RRSM} = 1500 V$	_	100	_	$\mu$ <b>A</b>
Reverse Recovery Time	t <sub>rr</sub>	$I_F = 20 \text{mA}, I_R = 1 \text{mA}$	_	_	10	μs

## **MARKING**



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